1. General description

Logic level N-channel MOSFET in an LFPAK56 (Power SO8) package using TrenchMOS technology. This product is designed and qualified for use in a wide range of power supply & motor control equipment.

2. Features and benefits

- Advanced TrenchMOS provides low $R_{DSon}$ and low gate charge
- Logic level gate operation
- Avalanche rated, 100 % tested
- LFPAK provides maximum power density in a Power SO8 package

3. Applications

- Synchronous rectification in power supply equipment
- Chargers & adaptors with $V_{out} < 10$ V
- Fast charge & USB-PD applications
- Battery powered motor control
- LED lighting & TV backlight

4. Quick reference data

<table>
<thead>
<tr>
<th>Symbol</th>
<th>Parameter</th>
<th>Conditions</th>
<th>Min</th>
<th>Typ</th>
<th>Max</th>
<th>Unit</th>
</tr>
</thead>
<tbody>
<tr>
<td>$V_{DS}$</td>
<td>drain-source voltage</td>
<td>$25 \ ^\circ C \leq T_j \leq 175 \ ^\circ C$</td>
<td>-</td>
<td>-</td>
<td>100</td>
<td>V</td>
</tr>
<tr>
<td>$I_D$</td>
<td>drain current</td>
<td>$V_{GS} = 5 \ V; T_{mb} = 25 \ ^\circ C; \ Fig. \ 2$</td>
<td>-</td>
<td>-</td>
<td>56</td>
<td>A</td>
</tr>
<tr>
<td>$P_{tot}$</td>
<td>total power dissipation</td>
<td>$T_{mb} = 25 \ ^\circ C; \ Fig. \ 1$</td>
<td>-</td>
<td>-</td>
<td>167</td>
<td>W</td>
</tr>
</tbody>
</table>

**Static characteristics**

$R_{DSon}$ drainage on-state resistance | $V_{GS} = 5 \ V; I_D = 15 \ A; T_j = 25 \ ^\circ C; \ Fig. \ 11$ | - | 14.6 | 19 | mΩ |

**Dynamic characteristics**

$Q_{GD}$ gate-drain charge | $I_D = 15 \ A; V_{DS} = 80 \ V; V_{GS} = 5 \ V; T_j = 25 \ ^\circ C; \ Fig. \ 13; \ Fig. \ 14$ | - | 14.1 | - | nC |
5. Pinning information

Table 2. Pinning information

<table>
<thead>
<tr>
<th>Pin</th>
<th>Symbol</th>
<th>Description</th>
<th>Simplified outline</th>
<th>Graphic symbol</th>
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<tr>
<td>1</td>
<td>S</td>
<td>source</td>
<td></td>
<td></td>
</tr>
<tr>
<td>2</td>
<td>S</td>
<td>source</td>
<td></td>
<td></td>
</tr>
<tr>
<td>3</td>
<td>S</td>
<td>source</td>
<td></td>
<td></td>
</tr>
<tr>
<td>4</td>
<td>G</td>
<td>gate</td>
<td></td>
<td></td>
</tr>
<tr>
<td>mb</td>
<td>D</td>
<td>mounting base; connected to drain</td>
<td></td>
<td></td>
</tr>
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</table>

6. Ordering information

Table 3. Ordering information

<table>
<thead>
<tr>
<th>Type number</th>
<th>Package</th>
<th>Name Description</th>
<th>Version</th>
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</thead>
<tbody>
<tr>
<td>PSMN019-100YL</td>
<td>LFPAK56; Power-SO8</td>
<td>Plastic single-ended surface-mounted package (LFPAK56; Power-SO8); 4 leads</td>
<td>SOT669</td>
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7. Marking

Table 4. Marking codes

<table>
<thead>
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<th>Type number</th>
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<tbody>
<tr>
<td>PSMN019-100YL</td>
<td>19L100</td>
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</table>

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

<table>
<thead>
<tr>
<th>Symbol</th>
<th>Parameter</th>
<th>Conditions</th>
<th>Min</th>
<th>Max</th>
<th>Unit</th>
</tr>
</thead>
<tbody>
<tr>
<td>( V_{DS} )</td>
<td>drain-source voltage</td>
<td>( 25 , ^\circ C \leq T_j \leq 175 , ^\circ C )</td>
<td>-</td>
<td>100</td>
<td>V</td>
</tr>
<tr>
<td>( V_{DGR} )</td>
<td>drain-gate voltage</td>
<td>( R_{GS} = 20 , k\Omega )</td>
<td>-</td>
<td>100</td>
<td>V</td>
</tr>
<tr>
<td>( V_{GS} )</td>
<td>gate-source voltage</td>
<td>-20</td>
<td>20</td>
<td>V</td>
<td></td>
</tr>
<tr>
<td>( P_{\text{tot}} )</td>
<td>total power dissipation</td>
<td>( T_{mb} = 25 , ^\circ C ); [Fig. 1]</td>
<td>-</td>
<td>167</td>
<td>W</td>
</tr>
<tr>
<td>( I_D )</td>
<td>drain current</td>
<td>( V_{GS} = 5 , V ); ( T_{mb} = 25 , ^\circ C ); [Fig. 2]</td>
<td>-</td>
<td>56</td>
<td>A</td>
</tr>
<tr>
<td>( I_{DM} )</td>
<td>peak drain current</td>
<td>( V_{GS} = 5 , V ); ( T_{mb} = 100 , ^\circ C ); [Fig. 2]</td>
<td>-</td>
<td>40</td>
<td>A</td>
</tr>
<tr>
<td>( T_{stg} )</td>
<td>storage temperature</td>
<td>pulsed; ( t_p \leq 10 , \mu s ); ( T_{mb} = 25 , ^\circ C ); [Fig. 3]</td>
<td>-</td>
<td>226</td>
<td>A</td>
</tr>
</tbody>
</table>

-55 | 175 | °C |
<table>
<thead>
<tr>
<th>Symbol</th>
<th>Parameter</th>
<th>Conditions</th>
<th>Min</th>
<th>Max</th>
<th>Unit</th>
</tr>
</thead>
<tbody>
<tr>
<td>$T_J$</td>
<td>junction temperature</td>
<td></td>
<td>-55</td>
<td>175</td>
<td>°C</td>
</tr>
</tbody>
</table>

**Source-drain diode**

- $I_S$: source current  
  - $T_{mb} = 25$ °C  
  - Min: -  
  - Max: 56 A

- $I_{SM}$: peak source current  
  - pulsed; $t_p \leq 10 \mu$s; $T_{mb} = 25$ °C  
  - Min: -  
  - Max: 226 A

**Avalanche ruggedness**

- $E_{DS(AL)S}$: non-repetitive drain-source avalanche energy  
  - $I_D = 56$ A; $V_{sup} \leq 100$ V; $R_{GS} = 50$ Ω; $V_{GS} = 5$ V; $T_{j(init)} = 25$ °C; unclamped; Fig. 4  
  - Min: 94.1 mJ

[1] Single-pulse avalanche rating limited by maximum junction temperature of 175 °C.  
[2] Refer to application note AN10273 for further information.

![Normalized total power dissipation as a function of mounting base temperature](image1.png)

![Continuous drain current as a function of mounting base temperature](image2.png)
Fig. 3. Safe operating area; continuous and peak drain currents as a function of drain-source voltage

\[ T_{\text{mb}} = 25^\circ \text{C}, \quad I_{\text{DM}} \text{ is a single pulse} \]

Fig. 4. Avalanche rating; avalanche current as a function of avalanche time

\[ (1) \quad T_j(\text{init}) = 25^\circ \text{C}; \quad (2) \quad T_j(\text{init}) = 150^\circ \text{C}; \quad (3) \quad \text{Repetitive Avalanche} \]

9. Thermal characteristics

<table>
<thead>
<tr>
<th>Symbol</th>
<th>Parameter</th>
<th>Conditions</th>
<th>Min</th>
<th>Typ</th>
<th>Max</th>
<th>Unit</th>
</tr>
</thead>
<tbody>
<tr>
<td>R(_{\text{th(j-mb)}})</td>
<td>thermal resistance from junction to mounting base</td>
<td>Fig. 5</td>
<td></td>
<td></td>
<td></td>
<td>K/W</td>
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</tbody>
</table>
10. Characteristics

Table 7. Characteristics

<table>
<thead>
<tr>
<th>Symbol</th>
<th>Parameter</th>
<th>Conditions</th>
<th>Min</th>
<th>Typ</th>
<th>Max</th>
<th>Unit</th>
</tr>
</thead>
<tbody>
<tr>
<td><strong>Static characteristics</strong></td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>$V_{(BR)DSS}$</td>
<td>drain-source breakdown voltage</td>
<td>$I_D = 250 \mu A; V_{GS} = 0 \ V; T_j = 25 \ ^\circ C$</td>
<td>100</td>
<td>-</td>
<td>-</td>
<td>V</td>
</tr>
<tr>
<td></td>
<td></td>
<td>$I_D = 250 \mu A; V_{GS} = 0 \ V; T_j = -55 \ ^\circ C$</td>
<td>90</td>
<td>-</td>
<td>-</td>
<td>V</td>
</tr>
<tr>
<td>$V_{GS(th)}$</td>
<td>gate-source threshold voltage</td>
<td>$I_D = 1 \ mA; V_{DS}=V_{GS}; T_j = 25 \ ^\circ C$; [Fig. 9; Fig. 10]</td>
<td>1.4</td>
<td>1.7</td>
<td>2.1</td>
<td>V</td>
</tr>
<tr>
<td></td>
<td></td>
<td>$I_D = 1 \ mA; V_{DS}=V_{GS}; T_j = -55 \ ^\circ C$; [Fig. 9]</td>
<td>-</td>
<td>-</td>
<td>2.45</td>
<td>V</td>
</tr>
<tr>
<td></td>
<td></td>
<td>$I_D = 1 \ mA; V_{DS}=V_{GS}; T_j = 175 \ ^\circ C$; [Fig. 9]</td>
<td>0.5</td>
<td>-</td>
<td>-</td>
<td>V</td>
</tr>
<tr>
<td>$I_{DSS}$</td>
<td>drain leakage current</td>
<td>$V_{DS} = 100 \ V; V_{GS} = 0 \ V; T_j = 175 \ ^\circ C$</td>
<td>-</td>
<td>-</td>
<td>500</td>
<td>$\mu A$</td>
</tr>
<tr>
<td></td>
<td></td>
<td>$V_{DS} = 100 \ V; V_{GS} = 0 \ V; T_j = 25 \ ^\circ C$</td>
<td>-</td>
<td>0.04</td>
<td>10</td>
<td>$\mu A$</td>
</tr>
<tr>
<td>$I_{GSS}$</td>
<td>gate leakage current</td>
<td>$V_{GS} = 16 \ V; V_{DS} = 0 \ V; T_j = 25 \ ^\circ C$</td>
<td>-</td>
<td>2</td>
<td>100</td>
<td>nA</td>
</tr>
<tr>
<td></td>
<td></td>
<td>$V_{GS} = -16 \ V; V_{DS} = 0 \ V; T_j = 25 \ ^\circ C$</td>
<td>-</td>
<td>2</td>
<td>100</td>
<td>nA</td>
</tr>
<tr>
<td>$R_{DSon}$</td>
<td>drain-source on-state resistance</td>
<td>$V_{GS} = 5 \ V; I_D = 15 \ A; T_j = 25 \ ^\circ C$; [Fig. 11]</td>
<td>-</td>
<td>14.6</td>
<td>19</td>
<td>m$\Omega$</td>
</tr>
<tr>
<td></td>
<td></td>
<td>$V_{GS} = 10 \ V; I_D = 15 \ A; T_j = 25 \ ^\circ C$; [Fig. 11]</td>
<td>-</td>
<td>14</td>
<td>18</td>
<td>m$\Omega$</td>
</tr>
<tr>
<td></td>
<td></td>
<td>$V_{GS} = 5 \ V; I_D = 15 \ A; T_j = 175 \ ^\circ C$; [Fig. 11; Fig. 12]</td>
<td>-</td>
<td>-</td>
<td>52.4</td>
<td>m$\Omega$</td>
</tr>
<tr>
<td><strong>Dynamic characteristics</strong></td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>$Q_{G(tot)}$</td>
<td>total gate charge</td>
<td>$I_D = 15 \ A; V_{DS} = 80 \ V; V_{GS} = 10 \ V$; $T_j = 25 \ ^\circ C$; [Fig. 13; Fig. 14]</td>
<td>-</td>
<td>72.4</td>
<td>-</td>
<td>nC</td>
</tr>
<tr>
<td></td>
<td></td>
<td>$I_D = 15 \ A; V_{DS} = 80 \ V; V_{GS} = 5 \ V$; $T_j = 25 \ ^\circ C$; [Fig. 13; Fig. 14]</td>
<td>-</td>
<td>39</td>
<td>-</td>
<td>nC</td>
</tr>
<tr>
<td>$Q_{GS}$</td>
<td>gate-source charge</td>
<td>$I_D = 15 \ A; V_{DS} = 80 \ V; V_{GS} = 10 \ V$; $T_j = 25 \ ^\circ C$; [Fig. 13; Fig. 14]</td>
<td>-</td>
<td>8.5</td>
<td>-</td>
<td>nC</td>
</tr>
</tbody>
</table>
### Symbol Parameter

<table>
<thead>
<tr>
<th>Symbol</th>
<th>Parameter</th>
<th>Conditions</th>
<th>Min</th>
<th>Typ</th>
<th>Max</th>
<th>Unit</th>
</tr>
</thead>
<tbody>
<tr>
<td>Q_{GD}</td>
<td>gate-drain charge</td>
<td></td>
<td>-</td>
<td>14.1</td>
<td>-</td>
<td>nC</td>
</tr>
<tr>
<td>C_{iss}</td>
<td>input capacitance</td>
<td>V_{DS} = 25 V; V_{GS} = 0 V; f = 1 MHz; T_j = 25 °C; <strong>Fig. 15</strong></td>
<td>-</td>
<td>3814</td>
<td>5085</td>
<td>pF</td>
</tr>
<tr>
<td>C_{oss}</td>
<td>output capacitance</td>
<td>T_j = 25 °C; Fig. 15</td>
<td>-</td>
<td>222</td>
<td>266</td>
<td>pF</td>
</tr>
<tr>
<td>C_{rss}</td>
<td>reverse transfer capacitance</td>
<td>R_{G(extra)} = 5 Ω; V_{GS} = 5 V; R_{Q(on)} = 5 Ω; T_j = 25 °C</td>
<td>-</td>
<td>133</td>
<td>182</td>
<td>pF</td>
</tr>
<tr>
<td>t_{d(on)}</td>
<td>turn-on delay time</td>
<td>V_{DS} = 80 V; R_L = 5 Ω; V_{GS} = 5 V; R_{Q(on)} = 5 Ω; T_j = 25 °C</td>
<td>-</td>
<td>18.5</td>
<td>-</td>
<td>ns</td>
</tr>
<tr>
<td>t_r</td>
<td>rise time</td>
<td></td>
<td>-</td>
<td>36.8</td>
<td>-</td>
<td>ns</td>
</tr>
<tr>
<td>t_{d(off)}</td>
<td>turn-off delay time</td>
<td>V_{DS} = 25 V; T_j = 25 °C</td>
<td>-</td>
<td>59.6</td>
<td>-</td>
<td>ns</td>
</tr>
<tr>
<td>t_f</td>
<td>fall time</td>
<td></td>
<td>-</td>
<td>34.3</td>
<td>-</td>
<td>ns</td>
</tr>
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### Source-drain diode

<table>
<thead>
<tr>
<th>Symbol</th>
<th>Parameter</th>
<th>Conditions</th>
<th>Min</th>
<th>Typ</th>
<th>Max</th>
<th>Unit</th>
</tr>
</thead>
<tbody>
<tr>
<td>V_{SD}</td>
<td>source-drain voltage</td>
<td>I_S = 15 A; V_{GS} = 0 V; T_j = 25 °C; <strong>Fig. 16</strong></td>
<td>-</td>
<td>0.8</td>
<td>1.2</td>
<td>V</td>
</tr>
<tr>
<td>t_{rr}</td>
<td>reverse recovery time</td>
<td>I_S = 15 A; dI_S/dt = -100 A/µs; V_{GS} = 0 V; V_{DS} = 25 V; T_j = 25 °C</td>
<td>-</td>
<td>38</td>
<td>-</td>
<td>ns</td>
</tr>
<tr>
<td>Q_r</td>
<td>recovered charge</td>
<td>V_{DS} = 25 V; T_j = 25 °C</td>
<td>-</td>
<td>56</td>
<td>-</td>
<td>nC</td>
</tr>
</tbody>
</table>

**Fig. 6.** Output characteristics; drain current as a function of drain-source voltage; typical values

**Fig. 7.** Drain-source on-state resistance as a function of gate-source voltage; typical values

T_j = 25 °C; I_D = 15 A
N-channel 100 V, 19 mΩ logic level MOSFET in LFPAK56

**Fig. 8.** Transfer characteristics; drain current as a function of gate-source voltage; typical values

\[ V_{DS} = 10\text{V} \]

**Fig. 9.** Gate-source threshold voltage as a function of junction temperature

\[ I_D = 1\text{mA}; \; V_{DS} = V_{GS} \]

**Fig. 10.** Sub-threshold drain current as a function of gate-source voltage

\[ T_J = 25^\circ\text{C}; \; V_{DS} = 5\text{V} \]

**Fig. 11.** Drain-source on-state resistance as a function of drain current; typical values

\[ T_J = 25^\circ\text{C}; \; t_p = 300\text{\mu s} \]
Fig. 12. Normalized drain-source on-state resistance factor as a function of junction temperature

\[ a = \frac{R_{DSon}}{R_{DSon}(25^\circ C)} \]

Fig. 13. Gate-source voltage as a function of gate charge; typical values

\[ T_J = 25^\circ C, \quad I_D = 15A \]

Fig. 14. Gate charge waveform definitions

Fig. 15. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values

\[ V_{GS} = 0V; \quad f = 1MHz \]
Fig. 16. Source (diode forward) current as a function of source-drain (diode forward) voltage; typical values

\[ V_{GS} = 0V \]
11. Package outline

**Plastic single-ended surface-mounted package (LFPAK56; Power-SO8); 4 leads**

<table>
<thead>
<tr>
<th>Unit(^{(1)})</th>
<th>A</th>
<th>A(_1)</th>
<th>A(_2)</th>
<th>A(_3)</th>
<th>b</th>
<th>b(_2)</th>
<th>b(_3)</th>
<th>c</th>
<th>D(_1)((^{(1)}))</th>
<th>D(_2)((^{(1)}))</th>
<th>E(^{(1)})</th>
<th>E(_1)((^{(1)}))</th>
<th>e</th>
<th>H</th>
<th>L</th>
<th>L(_1)</th>
<th>L(_2)</th>
<th>w</th>
<th>y</th>
</tr>
</thead>
<tbody>
<tr>
<td>mm max</td>
<td>1.20</td>
<td>0.15</td>
<td>1.10</td>
<td>0.50</td>
<td>4.41</td>
<td>2.2</td>
<td>0.9</td>
<td>0.25</td>
<td>0.30</td>
<td>4.10</td>
<td>4.20</td>
<td>5.0</td>
<td>3.3</td>
<td>6.2</td>
<td>0.85</td>
<td>1.3</td>
<td>1.3</td>
<td>0.25</td>
<td>0.1</td>
</tr>
<tr>
<td>mm nom</td>
<td>0.25</td>
<td></td>
<td></td>
<td></td>
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<tr>
<td>mm min</td>
<td>1.01</td>
<td>0.00</td>
<td>0.95</td>
<td>0.05</td>
<td>3.62</td>
<td>2.0</td>
<td>0.7</td>
<td>0.19</td>
<td>0.24</td>
<td>3.80</td>
<td>4.8</td>
<td>3.1</td>
<td>5.8</td>
<td>5.8</td>
<td>0.40</td>
<td>0.8</td>
<td>0.8</td>
<td></td>
<td></td>
</tr>
</tbody>
</table>

**Note**
1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.

**Fig. 17. Package outline LFPAK56; Power-SO8 (SOT669)**
12. Legal information

12.1 Data sheet status

<table>
<thead>
<tr>
<th>Document status</th>
<th>Product status</th>
<th>Definition</th>
</tr>
</thead>
<tbody>
<tr>
<td>Objective [short] data sheet</td>
<td>Development</td>
<td>This document contains data from the objective specification for product development.</td>
</tr>
<tr>
<td>Preliminary [short] data sheet</td>
<td>Qualification</td>
<td>This document contains data from the preliminary specification.</td>
</tr>
<tr>
<td>Product [short] data sheet</td>
<td>Production</td>
<td>This document contains the product specification.</td>
</tr>
</tbody>
</table>

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term ‘short data sheet’ is explained in section “Definitions”.

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nexperia.com.

12.2 Definitions

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For more information, please visit: http://www.nexperia.com
For sales office addresses, please send an email to: salesaddresses@nexperia.com
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